Introduction
This module guide will enable you to effectively use a module in your own design. Upon completion of this
guide, you will be able to add this module to your own design, configure it correctly for the target application
and write code, using the included application project code as a reference and efficient starting point.
References to more detailed API descriptions and suggestions of other application projects that illustrate
more advanced uses of the module are available in the Renesas Synergy™ Knowledge Base (as described
in the References section in this document) and should be valuable resources for creating more complex
designs.

There are two separate Flash modules: r_flash_lp and r_flash_hp. The High-Performance Flash module
(Flash_HP) is used for programming the S7 and S5 MCU Series. The Low-Power Flash module (Flash_LP)
is used for programming the S3 and S1 MCU Series. The two are not interchangeable, although the APIs
and other features of the modules are very similar. This guide covers the operation of both HAL modules.

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1. Flash HAL Module Features

The Flash HAL modules APIs allow an application to read, write, and erase both the data and ROM flash areas that reside within the MCU. The amount of flash memory available varies across MCU parts, but the API functions apply to all devices. Key features of the Flash HAL modules include:

- Support for block erasing, reading, writing, and blank checking of code flash (ROM).
- Support for both blocking and non-blocking, erasing, reading, writing, and blank checking of data flash.
- Support for blocking erasing, reading, writing, and blank checking of code flash.
- Support for callback functions for completion of non-blocking data-flash operations.
- Support for access window (write protection) for ROM Flash, allowing only specified areas of code flash to be erased or written.
- Support for boot block-swapping, which allows safe rewriting of the startup program without first erasing it.

2. Flash HAL Module APIs Overview

The Flash HAL module defines APIs for several operations including opening, reading, erasing, and closing the flash memory. A complete list of the available APIs, an example API call, and a short description of each can be found in the following table. A table of status return values follows the API summary table.

Table 1. Flash HAL Module API Summary

<table>
<thead>
<tr>
<th>Function Name</th>
<th>Example API Call and Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>.open</td>
<td>g_flash0.p_api-&gt;open(g_flash0.p_ctrl, g_flash0.p_cfg); Open FLASH device.</td>
</tr>
<tr>
<td>.write</td>
<td>g_flash0.p_api-&gt;write(g_flash0.p_ctrl, (uint32_t) write_buffer, FLASH_CF_32KB_BLOCK55, CODE_BLOCK_SIZE_32KB); Write FLASH device.</td>
</tr>
<tr>
<td>.read</td>
<td>g_flash0.p_api-&gt;read(g_flash0.p_ctrl, read_buffer, DATA_FLASH_ADDR, num_bytes); Read FLASH device.</td>
</tr>
<tr>
<td>.erase</td>
<td>g_flash0.p_api-&gt;erase(g_flash0.p_ctrl, FLASH_CF_32KB_BLOCK55, num_sectors); Erase FLASH device.</td>
</tr>
</tbody>
</table>
Function Name | Example API Call and Description
--- | ---
.blankCheck | `g_flash0.p_api->blankCheck(g_flash0.p_ctrl, FLASH_CF_32KB_BLOCK55, FLASH_DATA_BLOCK_SIZE, &blankCheck);`  
Blank check FLASH device.
.close | `g_flash0.p_api->close(g_flash0.p_ctrl);`  
Close FLASH device.
.statusGet | `g_flash0.p_api->statusGet(g_flash0.p_ctrl);`  
Get Status for FLASH device.
.accessWindowSet | `g_flash0.p_api->accessWindowSet(g_flash0.p_ctrl, FLASH_CF_32KB_BLOCK1, FLASH_CF_32KB_BLOCK3);`  
Set Access Window for FLASH device.
.accessWindowClear | `g_flash0.p_api->accessWindowClear(g_flash0.p_ctrl);`  
Clear any existing code-flash access window for FLASH device.
.idCodeSet | `g_flash0.p_api->idCodeSet(g_flash0.p_ctrl, id_bytes, mode);`  
Write the ID code provided to the id coderegisters.
.reset | `g_flash0.p_api->reset(g_flash0.p_ctrl);`  
Reset function for FLASH device.
.updateFlashClockFreq | `g_flash0.p_api->updateFlashClockFreq(g_flash0.p_ctrl);`  
Update Flash clock frequency (FCLK) and recalculate timeout values.
.startupAreaSelect | `g_flash0.p_api->startupAreaSelect(g_flash0.p_ctrl, FLASH_STARTUP_AREA_BLOCK1);`  
Select which block - Default (Block 0) or Alternate (Block 1) is used as the start-up area block.  
Refer to the table below for all the possible values for parameter2.
.versionGet | `g_flash0.p_api->versionGet(&version);`  
Retrieve the API version using the version pointer.

Note: For details on operation and definitions for the function data structures, typedefs, defines, API data, API structures and function variables, review the *SSP User’s Manual* available as described in the References section in this document.

### Table 2. .setupAreaSelect Parameter2 Options

<table>
<thead>
<tr>
<th>Swap Type</th>
<th>Is_temporary</th>
<th>Operation</th>
</tr>
</thead>
<tbody>
<tr>
<td>FLASH_STARTUP_AREA_BLOCK0</td>
<td>False</td>
<td>On next reset, Startup area is Block 0.</td>
</tr>
<tr>
<td>FLASH_STARTUP_AREA_BLOCK0</td>
<td>False</td>
<td>On next reset, Startup area is Block 0.</td>
</tr>
<tr>
<td>FLASH_STARTUP_AREA_BLOCK1</td>
<td>False</td>
<td>On next reset, Startup area is Block 1.</td>
</tr>
<tr>
<td>FLASH_STARTUP_AREA_BLOCK1</td>
<td>True</td>
<td>Startup area is immediately, but temporarily switched to Block 1.</td>
</tr>
<tr>
<td>FLASH_STARTUP_AREA_BTFLG</td>
<td>True</td>
<td>Startup area is immediately, but temporarily switched to the Block determined by the Configuration BTFLG.</td>
</tr>
</tbody>
</table>

### Table 3. Status Return Values

<table>
<thead>
<tr>
<th>Name</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>SSP_SUCCESS</td>
<td>Function successful.</td>
</tr>
<tr>
<td>SSP_ERR_IN_USE</td>
<td>Device in use error.</td>
</tr>
<tr>
<td>SSP_FLASH_ERR_FAILURE</td>
<td>Flash failure error.</td>
</tr>
<tr>
<td>SSP_ERR_FCLK</td>
<td>FCLK must be a minimum of 4 MHz for Flash operations.</td>
</tr>
<tr>
<td>SSP_ERR_TIMEOUT</td>
<td>Timeout error.</td>
</tr>
<tr>
<td>SSP_ERR_INVALID_SIZE</td>
<td>Invalid size error.</td>
</tr>
<tr>
<td>SSP_ERR_INVALID_ADDRESS</td>
<td>Invalid address error.</td>
</tr>
</tbody>
</table>
### Flash HAL Module Operational Overview

The Flash API makes the process of programming and erasing on-chip flash areas easy. Both code (User ROM) and data-flash areas are supported. The API, in its simplest form, can be used to perform blocking erase and program operations. The term **blocking** means that when a program or erase function is called, the function does not return until the operation has finished. This API supports blocking for both code and data-flash, with BGO (background-mode operation) available for data-flash operations only. When a code-flash operation is on-going, you cannot access that code-flash area. If you attempt to access the code-flash area while a code-flash operation is in progress, the flash-control unit transitions into an error state.

It is important to keep in mind that even though a code-flash operation is blocking, there are several situations where the code-flash could still end up being accessed while the operation is blocking. These must be prevented. These include:

- Vector table access if the Vector table is located in the ROM.
- ROM access by an interrupt vectoring to a ROM address, even if the vector table itself is not in ROM.

A multithreaded application where multiple threads are allowed to continue to run while a code-flash operation is blocking.

### 3.1 Flash HAL Module Important Operational Notes and Limitations

- **startupAreaSelect()** swaps data in to block 0. Be sure that the swapped-in data is valid if you use `startupAreaSelect()`.

### 3.1.1 Flash HAL Module Operational Notes

#### Data-Flash BGO Precautions

When using the data-flash BGO, the User ROM, RAM, and external memory can still be accessed. You must ensure that the data-flash is not accessed during a data-flash operation. This includes interrupts that may access the data-flash.

#### Code-Flash Precautions

BGO mode is not supported for code-flash, so a code-flash operation is not returned before the operation has completed. By default, the vector table resides in the user ROM (code-flash). If an interrupt occurs during the ROM operation, then ROM is accessed to retrieve the interrupt’s starting address and an error occurs.
The simplest work-around is to disable interrupts during code-flash operations. Another option is to copy the vector table to RAM, update the VTOR (Vector Table Offset Register) accordingly and ensure that any interrupt service routines execute out of RAM. Similarly, you must ensure that if in a multithreaded environment, threads running from ROM cannot become active while a code-flash operation is in progress.

**Blank Checking**

The `blankCheck` API function checks whether code or data-flash contents are blank. It is not possible to write to flash (code or data) without first erasing it. The `blankCheck` function determines whether a specified area is blank and therefore writable. In almost all cases, it is not sufficient to compare flash contents to 0xFF to determine whether the area is blank. The one exception is Flash HP code-flash. A 0xFF in Flash_HP code-flash does indicate blank. Renesas strongly recommends using the `blankCheck` API function in all cases.

**Flash Status**

The `statusGet` API function allows the application to query the ‘Ready’ status of the flash. This is useful in data-flash BGO operations when you choose not to use a callback function, so there is no asynchronous notification of a completed data-flash operation. In this case, the data-flash is configured to operate in BGO mode, so once the operation is started (an erase, for example), the call returns immediately with the operation executing in the background. By calling the `statusGet` API function, you can determine when the operation has safely completed or generated an error, and it is now safe to proceed with another flash operation.

**Swap Blocks**

The `startupAreaSelect` API function allows the user to select which block - default (Block 0) or alternate (Block 1) - is used as the startup-area block. The provided parameters determine which block becomes the active startup block and whether that action is immediate (but temporary) or permanent, subsequent to the next reset.

Doing a temporary switch might appear to have limited usefulness; however, if there is an access window in place such that Block 0 is write-protected, then you could do a temporary switch, update the block, and switch them back without having to touch the access window.

**Flash Clock (FCLK)**

The FCLK is the clock used by the Flash peripheral in performing all Flash operations. It must be >= 4 MHz for successful flash operations. As part of the `open` function, the Flash clock is checked, and if < 4 MHz `open` API returns SSP_ERR_FCLK. Once the Flash API has been opened, if the FCLK frequency is changed, the `updateFlashClockFreq` API function must be called to inform the API of the change. Failure to do so could result in flash operation failures and possibly damage the part.

**Interrupts**

Enable the flash ready interrupt only if you plan to use the data-flash BGO. In this mode, the application can initiate a data-flash operation and then be asynchronously notified of its completion, or an error, using a user-supplied callback function. The callback function is passed a structure containing event information that indicates the source of the callback event (that is FLASH_EVENT_ERASE_COMPLETE).

When the FLASH FRDYI interrupt is enabled, the corresponding ISR is defined in the flash driver. The ISR calls a user-callback function if one was registered with the `open` API.

Note: The Flash HP supports an additional flash-error interrupt and if the BGO mode is enabled for the FLASH HP then both FRDYI and FIFERR interrupts must be given a priority.

**AccessWindow**

An access window defines a contiguous area in code flash for which programming/erase is enabled. This area is on block boundaries with a starting and ending address being provided to `accessWindowSet`. The block containing the start address is the first block. The block containing the end address is the last block. The access window then becomes the first block – last block inclusive. Anything outside this range is write protected. Invalid address information provided to `accessWindowSet` returns SSP_ERR_INVALID_ADDRESS. An access window may be removed by calling the `accessWindowClear` API function.
3.1.2 Flash HAL Module Limitations

- The High-Performance Flash module (Flash_HP) is the API used for programming the S7 and S5 family of MCUs.
- The Low-Power Flash module (Flash_LP) is the API used for programming the S3 and S1 family of MCUs.

Refer to the latest SSP Release Note for any additional operational limitations for this module.

4. Including the Flash HAL Module in an Application

This section describes how to include the Flash HAL module in an application using the SSP Configurator.

Note: It is assumed you are familiar with creating a project, adding threads, adding a stack to a thread and configuring a block within the stack. If you are unfamiliar with any of these items, refer to the first few chapters of the SSP User’s Manual to learn how to manage each of these important steps in creating SSP-based applications.

To add the Flash Driver to an application, simply add it to a thread using the stacks selection sequence given in the following table. (The default name for the Flash Driver is g_flash0. This name can be changed in the associated Properties window.)

Table 4. Flash Driver Selection Sequence

<table>
<thead>
<tr>
<th>Resource</th>
<th>ISDE Tab</th>
<th>Stacks Selection Sequence</th>
</tr>
</thead>
<tbody>
<tr>
<td>g_flash0 Flash Driver on r_rflash_hp</td>
<td>Threads</td>
<td>New Stack &gt; Driver &gt; Storage &gt; Flash Driver on r_rflash_hp</td>
</tr>
<tr>
<td>g_flash0 Flash Driver on r_rflash_lp</td>
<td>Threads</td>
<td>New Stack &gt; Driver &gt; Storage &gt; Flash Driver on r_rflash_lp</td>
</tr>
</tbody>
</table>

When the Flash HAL modules on r_rflash_hp or r_rflash_lp are added to the thread stack as shown in the figure below, the configurator automatically adds any needed lower-level modules. Any drivers that need additional configuration information is box text highlighted in Red. Modules with a Gray band are individual modules that stand alone.

Note: The following figure shows both Flash HAL modules. Only one module should be used, depending on the selected MCU; they are only shown together for completeness.

![Flash HAL Module Stack](image)

5. Configuring the Flash HAL Module

The Flash HAL module must be configured by the user for the desired operation. The SSP configuration window automatically identifies (by highlighting the block in red) any required configuration selections, such as interrupts or operating modes, which must be configured for lower-level modules for successful operation. Only those properties that can be changed without causing conflicts are available for modification. Other properties are 'locked' and are not available for changes and are identified with a lock icon for the 'locked' property in the Properties window in the ISDE. This approach simplifies the configuration process and makes it much less error prone than previous 'manual' approaches to configuration. The available configuration settings and defaults for all the user-accessible properties are given in the Properties tab within the SSP configurator and are shown in the following tables for easy reference.
One of the properties most often identified as requiring a change is the interrupt priority; this configuration setting is available within the Properties window of the associated module. Simply select the indicated module and then view the **Properties** window; the interrupt settings are often toward the bottom of the properties list, so scroll down until they become available. Also note that the interrupt priorities listed in the Properties window in the ISDE include an indication as to the validity of the setting based on the targeted MCU (CM4 or CM0+). This level of detail is not included in the following configuration properties tables but is easily visible with the ISDE when configuring interrupt-priority levels.

**Note:** You may want to open your ISDE, create the module and explore the property settings in parallel with looking over the configuration table settings in the following tables. This helps to orient you and can be a useful ‘hands-on’ approach to learning the ins and outs of developing with SSP.

The Flash HAL Driver is implemented on one of two different modules, the `r_flash_hp` and the `r_flash_lp`, and the configuration settings for these implementations are given in the following tables.

**Table 5. Configuration Settings for the Flash HAL Module on r_flash_hp**

<table>
<thead>
<tr>
<th>ISDE Property</th>
<th>Value</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>Parameter Checking</td>
<td>BSP, Enabled, Disabled (Default: BSP)</td>
<td>Controls whether to include code for API parameter checking.</td>
</tr>
<tr>
<td>Code-flash Programming Enable</td>
<td>Enable, Disabled (Default: Disabled)</td>
<td>Controls whether or not code-flash programming is enabled. Disabling reduces the amount of ROM used by the API.</td>
</tr>
<tr>
<td>Name</td>
<td>g_flash0</td>
<td>Module name.</td>
</tr>
<tr>
<td>Data-flash Background Operation</td>
<td>Enabled, Disabled (Default: Enabled)</td>
<td>Enabling allows Flash API calls that reference data-flash to return immediately, with the operation continuing in the background.</td>
</tr>
<tr>
<td>Callback</td>
<td>NULL</td>
<td>Callback function called when a data-flash BGO operation completes or errors. A user callback function can be registered in open. Warning: Since the callback is called from an ISR, do not use blocking calls or lengthy processing. Spending excessive time in an ISR can affect the responsiveness of the system.</td>
</tr>
<tr>
<td>Flash Ready Interrupt Priority</td>
<td>Priority 0 (highest), Priority 1:2, Priority 3 (CM4: valid, CM0+: lowest- not valid if using ThreadX), Priority 4:14 (CM4: valid, CM0+: invalid), Priority 15 (CM4 lowest - not valid if using ThreadX, CM0+: invalid) (Default: Disabled)</td>
<td>Flash ready interrupt priority selection.</td>
</tr>
<tr>
<td>Flash Error Interrupt Priority</td>
<td>Priority 0 (highest), Priority 1:2, Priority 3 (CM4: valid, CM0+: lowest- not valid if using ThreadX), Priority 4:14 (CM4: valid, CM0+: invalid), Priority 15 (CM4 lowest - not valid if using ThreadX, CM0+: invalid) (Default: Disabled)</td>
<td>Flash error interrupt priority selection.</td>
</tr>
</tbody>
</table>

**Note:** The example values and defaults are for a project using the Synergy S7G2. Other MCUs may have different default values and available configuration settings.
Table 6. Configuration for the Flash HAL Module on r_flash_lp

<table>
<thead>
<tr>
<th>ISDE Property</th>
<th>Value</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>Parameter Checking</td>
<td>BSP, Enabled, Disabled</td>
<td>Controls whether to include code for API parameter checking.</td>
</tr>
<tr>
<td>Code-flash Programming Enable</td>
<td>Enable, Disabled</td>
<td>Controls whether or not code-flash programming is enabled. Disabling reduces the amount of ROM used by the API.</td>
</tr>
<tr>
<td></td>
<td>(Default: Enabled)</td>
<td></td>
</tr>
<tr>
<td>Name</td>
<td>g_flash0</td>
<td>Module name.</td>
</tr>
<tr>
<td>Data-flash Background Operation</td>
<td>Enabled, Disabled</td>
<td>Enabling allows Flash API calls that reference data-flash to return immediately, with the operation continuing in the background.</td>
</tr>
<tr>
<td></td>
<td>(Default: Enabled)</td>
<td></td>
</tr>
<tr>
<td>Callback</td>
<td>NULL</td>
<td>Callback function called when a data-flash BGO operation completes or errors. A user callback function can be registered in open. Warning: Since the callback is called from an ISR, do not use blocking calls or lengthy processing. Spending excessive time in an ISR can affect the responsiveness of the system.</td>
</tr>
<tr>
<td>Flash Ready Interrupt Priority</td>
<td>Priority 0 (highest), Priority 1:2, Priority 3 (CM4: valid, CM0+: lowest- not valid if using ThreadX), Priority 4:14 (CM4: valid, CM0+: invalid), Priority 15 (CM4 lowest - not valid if using ThreadX, CM0+: invalid) (Default: Disabled)</td>
<td>Flash ready interrupt priority selection.</td>
</tr>
</tbody>
</table>

Note: The example values and defaults are for a project using the Synergy S3A7 MCU. Other MCUs may have different default values and available configuration settings.

In some cases, settings other than the defaults can be desirable. For example, it might be useful to disable code-flash programming to reduce the code size of the driver.

5.1 Flash HAL Module Clock Configuration

Enable the flash-ready interrupt only if you plan to use the data-flash BGO (background mode operation.) In this mode, the application can initiate a data-flash operation and then be asynchronously notified of its completion (or an error) using a user-supplied callback function. The callback function is passed a structure containing event information that indicates the source of the callback event (for example, FLASH_EVENT_ERASE_COMPLETE.)

To enable interrupts, set the priority of the FCU > FRDYI interrupt on the ICU tab of the Project Configurator in e² studio. This sets BSP_IRQ_CFG_FCU_FRDYI in synergy_cfg/ssp_cfg/bsp/bsp_irq_cfg.h to the priority level selected.

When the FLASH FRDYI interrupt is enabled in the BSP, the corresponding ISR is defined in the Flash driver. The ISR calls a user-callback function if one was registered in open.

Note: Flash HP supports an additional flash-error interrupt and if BGO mode is enabled for FLASH HP, then both FRDYI and FIFERR interrupts must be given a priority.

5.2 Flash HAL Module Clock Configuration

The flash circuit uses FCLK as its clock. FCLK must be <= 4 MHz. If this clock rate changes after the flash open() function is called, then you must call updateFlashClockFreq() to inform the flash API of the change.
5.3 Flash HAL Module Pin Configuration
The flash circuit does not use any MCU pins.

6. Using the Flash HAL Module in an Application
Some typical steps in using the Flash HAL module in an application are as follows:
1. Initialize the Flash HAL using the open API.
2. Disable Interrupts.
3. Blank check a code flash area with the blankCheck API.
4. Erase one or more code-flash blocks with the erase API.
5. Write to code-flash with the write API.
6. Enable Interrupts.
7. Blank check a data flash area with the blankCheck API.
8. Erase one or more data-flash blocks using the erase API.
9. Write to data-flash using the write API.
10. Close using the close API if finished with all Flash operations.

Figure 3. Flow Diagram of a Typical Flash HP HAL Module Application

7. The Flash HAL Module Application Project
The application project associated with this module guide demonstrates the aforementioned steps in a full design. You may want to import and open the application project within the ISDE and view the configuration settings for the Flash HAL Module. You can also read over the code (in flash_hp_hal_mg.c/.h and flash_hp_hal_api_mg.h), which are used to illustrate the Flash HAL module APIs in a complete design.

The application project demonstrates the typical use of the Flash HAL module APIs. The application project HAL entry initializes the Flash HP HAL module; it also calls Flash HP application-entry function and after Flash HP operations are executed, the application project toggles the LED periodically.
The entry function to perform Flash operations is defined in `flash_hp_hal_mg.c`. It initializes semi-hosting if enabled from the header file, calls an open function call to initialize the Flash HAL module, and calls code/data-flash operations. After the flash operations are performed, the program gets back to the `hal_entry.c` to execute the LED toggle.

The code-flash function block includes APIs for the code-flash to blank check a sector, erase a sector, read data, write data, set the access window, and clear the access window. These APIs are used to demonstrate each operation and its results, enable semi-hosting to print the results with error codes in the **Console** window.

The data-flash function block includes uses of APIs for the data-flash to blank check a sector, erase a sector, write data, and read data. These APIs are used in a particular order to demonstrate each operation and its results. You can enable semi-hosting to print the results with error codes in the console. Also, this function block demonstrates BGO operations and the use of callback functions for the data-flash.

All the Flash HP HAL APIs are used in the `flash_hp_hal_api_mg.h` header file and the `flash_hp_hal_mg.h` header file contains macros for the Flash HP HAL application project.

### Table 7. Software and Hardware Resources Used by the Application Project

<table>
<thead>
<tr>
<th>Resource</th>
<th>Revision</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>e² studio</td>
<td>v7.3.0 or later</td>
<td>Integrated Solution Development Environment</td>
</tr>
<tr>
<td>SSP</td>
<td>v1.6.0 or later</td>
<td>Synergy Software Platform</td>
</tr>
<tr>
<td>IAR EW for Synergy</td>
<td>v8.23.3 or later</td>
<td>IAR Embedded Workbench® for Renesas Synergy™</td>
</tr>
<tr>
<td>SSC</td>
<td>v7.3.0 or later</td>
<td>Synergy Standalone Configurator</td>
</tr>
<tr>
<td>SK-S7G2</td>
<td>v3.0 to v3.3</td>
<td>Starter Kit</td>
</tr>
</tbody>
</table>

The following figures show simple Application Project flows.

**Figure 4. Flash HAL Module Application Project Flow Diagram**
The complete application project can be found using the link provided in the References section in this document. Locate `flash_hp_hal_mg.c` and `flash_hp_hal_api_mg.h` in the project once it has been imported into the ISDE. You can open this file within the ISDE and follow along with the description provided to help identify key uses of APIs.

As mentioned above, the `flash_hp_hal_mg.c` contains APIs to initialize Flash HP HAL and functions to execute data/code-flash operations. The code-flash function block demonstrates various code-flash operations. The code-flash operations function block uses the read, write, erase, blank check and set/clear flash access window operations. There is no particular flow of operations for the Flash HP. The APIs can be used standalone as per the application’s requirements.
The data-flash function block demonstrates various data-flash operations. The data-flash operations function block uses read, write, erase and blank check data-flash operations. There is no particular flow of operations for Flash HP for data-flash; the APIs can be used as standalone as per the application’s requirements. Both data and code-flash operations use the same APIs with respective flash addresses as parameters.

The last section is the user-callback function. Data-flash background operations (BGO) can be non-blocking, that is, the function call returns immediately after it is called and an interrupt is generated when the operation is completed. The callback function handles interrupts for the Flash HP and sets flags to be used in Flash operations.

The **flash_hp_hal_mg.h** file contains macro for memory addresses that are used in Flash APIs, write bytes, semi-hosting enable/disable and function prototypes.

Note: This description assumes that you are familiar with using printf() for the Debug Console with the Synergy Software Package. If you are unfamiliar with this, refer to *How do I Use Print() with the Debug Console in the Synergy Software Package* given in the References section in this document. Alternatively, the user can see results using the watch variables in the debug mode.

A few key properties are configured in this application project to support the required operations and the physical properties of the target board and MCU. The properties with the values set for this specific project are listed in the following table. You can also open the application project and view these settings in the Properties window as a hands-on exercise.
Table 8. Flash HAL Module Configuration Settings for the Application Project

<table>
<thead>
<tr>
<th>Resource</th>
<th>ISDE Property</th>
<th>Setting</th>
</tr>
</thead>
<tbody>
<tr>
<td>g_flash0 Flash Driver on r_flash_hp</td>
<td>Parameter Checking</td>
<td>Disabled</td>
</tr>
<tr>
<td></td>
<td>Code-flash Programming Enable</td>
<td>Enable</td>
</tr>
<tr>
<td></td>
<td>FCU FRDYI</td>
<td>Priority3</td>
</tr>
<tr>
<td></td>
<td>FCU FIFERR</td>
<td>Priority3</td>
</tr>
<tr>
<td></td>
<td>Name</td>
<td>g_flash0</td>
</tr>
<tr>
<td></td>
<td>Data-flash Background Operation</td>
<td>Enabled</td>
</tr>
<tr>
<td></td>
<td>Callback</td>
<td>BGO_Callback</td>
</tr>
</tbody>
</table>

8. Customizing the Flash HAL Module for a Target Application

Some user configuration settings are normally changed by the developer from those shown in the application project. For example, you can easily change the configuration settings for code-flash programming and data-flash background operations. If code-flash programming is not required in the user application, the user can disable code-flash programming. This also helps to make the code size smaller. The user can change the BGO and interrupt settings from the configuration properties for data-flash operations to select between blocking (non-BGO) or non-blocking (BGO) operations.

The application project writes to specific memory sectors of the code and data-flash. You can change API parameters to be the memory address of the sectors they want to work with.

9. Running the Flash HAL Module Application Project

To run the Flash HAL module application project and see it executed on a target kit, you can simply import it into your ISDE, compile and run debug. See Renesas Synergy™ Project Import Guide (r11an0023eu0121-synergy-ssp-import-guide.pdf, included in this package) for instructions on importing the project into e² studio or IAR EW for Synergy and building/running the application.

To implement the Flash HAL module application in a new project, follow the steps below for defining, configuring, auto-generating files, adding code, compiling and debugging on the target kit. The hands-on approach of following these steps can help make the development process with SSP more practical, while just reading over this guide tends to be more theoretical.

Note: The following steps are described in sufficient detail for someone experienced with the basic flow through the Synergy development process. If these steps are not familiar, refer to the first few chapters of the SSP User’s Manual for a description of how to accomplish these steps.

To create and run the Flash HAL module application project, simply follow these steps:

1. Import attached Example Project into e² studio or IAR EW for Synergy. For steps to import an example project, see Renesas Synergy™ Project Import Guide (r11an0023eu0121-synergy-ssp-import-guide.pdf, included in this package).
2. Compile the application without errors or warnings.
3. Connect to the host PC via a micro USB cable to J19 on SK-S7G2.
4. Start to debug the application.
5. The output can be viewed (see figure), if semi-hosting is enabled from the flash_hp_hal_mg.h file.

Note: LED1-3 toggles after flash operations are executed. By default, the application project executes data-flash operations. To execute code-flash operations, change the 1 to a 0 on line 533 in the flash_hp_hal_mg.c file.
Figure 7. Example Output from Flash HAL Module Application Project – Data-flash Operations BGO (Non-Blocking), Default Operation

Figure 8. Example Output from Flash HAL Module Application Project – Code-flash Operations
10. Flash HAL Module Conclusion

This module guide has provided all the background information needed to select, add, configure, and use the Flash HP/LP module in an example project. Many of these steps were time consuming and error-prone activities in previous generations of embedded systems. The Renesas Synergy™ Platform makes these steps much less time consuming and removes the common errors, like conflicting configuration settings or the incorrect selection of lower-level drivers. The use of high-level APIs (as demonstrated in the application project) illustrate additional development time savings by allowing work to begin at a high level and avoiding the time required in older development environments to use or, in some cases, create, lower-level drivers.

11. Flash HAL Module Next Steps

After you have mastered a simple Flash HP HAL Module application project, you may want to use the APIs that manipulates flash from the application during run time. (For example, a secondary bootloader.) These APIs can also be used to write and read the program status to flash memory at run time.

12. Flash HAL Module Reference Information


Links to all the most up-to-date r_flash module reference materials and resources are available on the Synergy Knowledge Base: https://en-us.knowledgebase.renesas.com/English_Content/Renesas_Synergy%E2%84%A2_Platform/Renesas_Synergy_Knowledge_Base/r__flash_Module_Guide_Resources.
Website and Support

Visit the following vanity URLs to learn about key elements of the Synergy Platform, download components and related documentation, and get support.

Synergy Software
- www.renesas.com/synergy/software
- Synergy Software Package www.renesas.com/synergy/ssp
- Software add-ons www.renesas.com/synergy/addons
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- Training www.renesas.com/synergy/training
- Videos www.renesas.com/synergy/videos
- Chat and web ticket www.renesas.com/synergy/resourcelibrary
13. Revision History

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<th>Date</th>
<th>Page</th>
<th>Summary</th>
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<td>1.00</td>
<td>May.15.17</td>
<td>-</td>
<td>Initial Release</td>
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<td>1.01</td>
<td>Aug.1.17</td>
<td>11</td>
<td>Update to Hardware and Software Resources Table</td>
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<tr>
<td>1.10</td>
<td>Nov.13.18</td>
<td>-</td>
<td>Changed Note before Fig 7 and changed Fig 7/8/9 order</td>
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<tr>
<td>1.20</td>
<td>Apr.29.19</td>
<td>-</td>
<td>Added new API information. Updated for SSP v1.6.0.</td>
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